DF051

FAST RECOVERY DIODE

APPLICATIONS

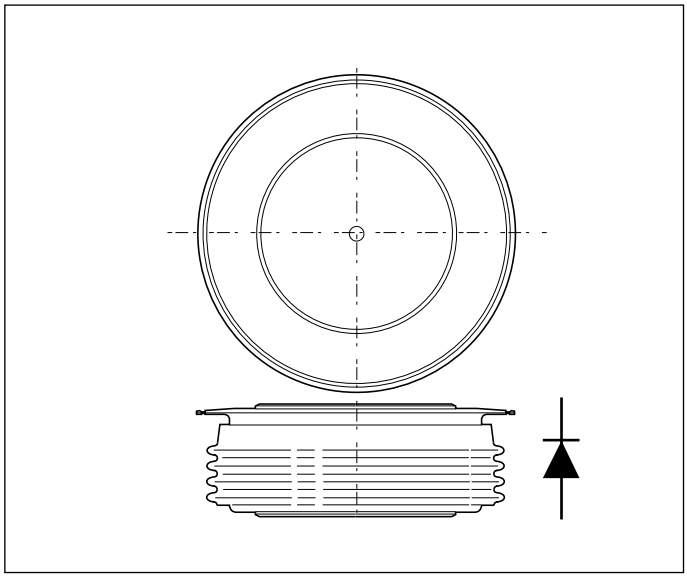
- Induction Heating.
- A.C. Motor Drives.
- Inverters And Choppers.
- Welding.
- High Frequency Rectification.
- UPS.

KEY PARAMETERS

V_{RRM}	2500V
$I_{F(AV)}$	1490A
I_{FSM}	14000A
Q_r	800μC
t_{rr}	5.0μs

FEATURES

- Double side cooling.
- High surge capability.
- Low recovery charge.



Outline type code: CB450.
See package outlines for further information.

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V_{RRM} V	Conditions
DF051 25 DF051 24 DF051 22 DF051 20	2500 2400 2200 2000	$V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available.

CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
Double Side Cooled				
$I_{F(AV)}$	Mean forward current	Half wave resistive load, T_{case} = 65°C	1490	A
$I_{F(RMS)}$	RMS value	T_{case} = 65°C	2340	A
I_F	Continuous (direct) forward current	T_{case} = 65°C	2160	A
Single Side Cooled (Anode side)				
$I_{F(AV)}$	Mean forward current	Half wave resistive load, T_{case} = 65°C	995	A
$I_{F(RMS)}$	RMS value	T_{case} = 65°C	1560	A
I_F	Continuous (direct) forward current	T_{case} = 65°C	1390	A

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I_{FSM}	Surge (non-repetitive) forward current	10ms half sine; with 0% $V_{RRM,}$ T_j = 150°C	14.0	kA
I^2t	I^2t for fusing		980 x 10^3	A^2s
I_{FSM}	Surge (non-repetitive) forward current	10ms half sine; with 50% $V_{RRM,}$ T_j = 150°C	11.2	kA
I^2t	I^2t for fusing		627 x 10^3	A^2s

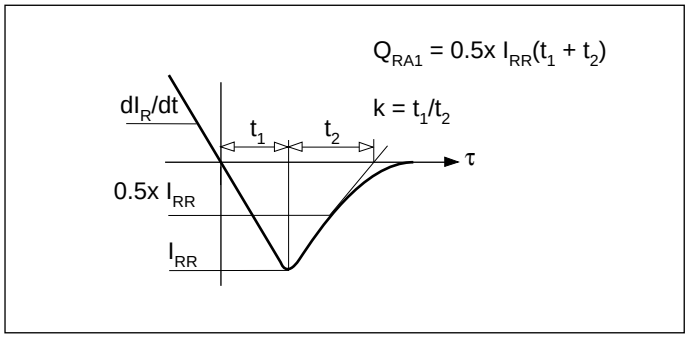
THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.018	°C/W
		Single side cooled	Anode dc	-	0.034	°C/W
			Cathode dc	-	0.038	°C/W
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 23.5kN with mounting compound	Double side	-	0.003	°C/W
			Single side	-	0.006	°C/W
T_{vj}	Virtual junction temperature	On-state (conducting)		-	150	°C
T_{stg}	Storage temperature range			-55	150	°C
-	Clamping force			21.0	25.0	kN

CHARACTERISTICS

Symbol	Parameter	Conditions	Typ.	Max.	Units
V_{FM}	Forward voltage	At 1500A peak, T_{case} = 25°C	-	1.85	V
I_{RRM}	Peak reverse current	At V_{RRM}, T_{case} = 150°C	-	100	mA
t_{rr}	Reverse recovery time	I_F = 1000A, di_{RR}/dt = 100A/µs T_{case} = 150°C, V_R = 100V	5.0	-	µs
Q_{RA1}	Recovered charge (50% chord)		-	800	µC
I_{RM}	Reverse recovery current		-	250	A
K	Soft factor		1.6	-	-
V_{TO}	Threshold voltage	At T_{vj} = 150°C	-	1.1	V
r_T	Slope resistance	At T_{vj} = 150°C	-	0.5	mΩ
V_{FRM}	Forward recovery voltage	di/dt = 1000A/µs, T_j = 125°C	-	-	V

DEFINITION OF K FACTOR AND Q_{RA1}



CURVES

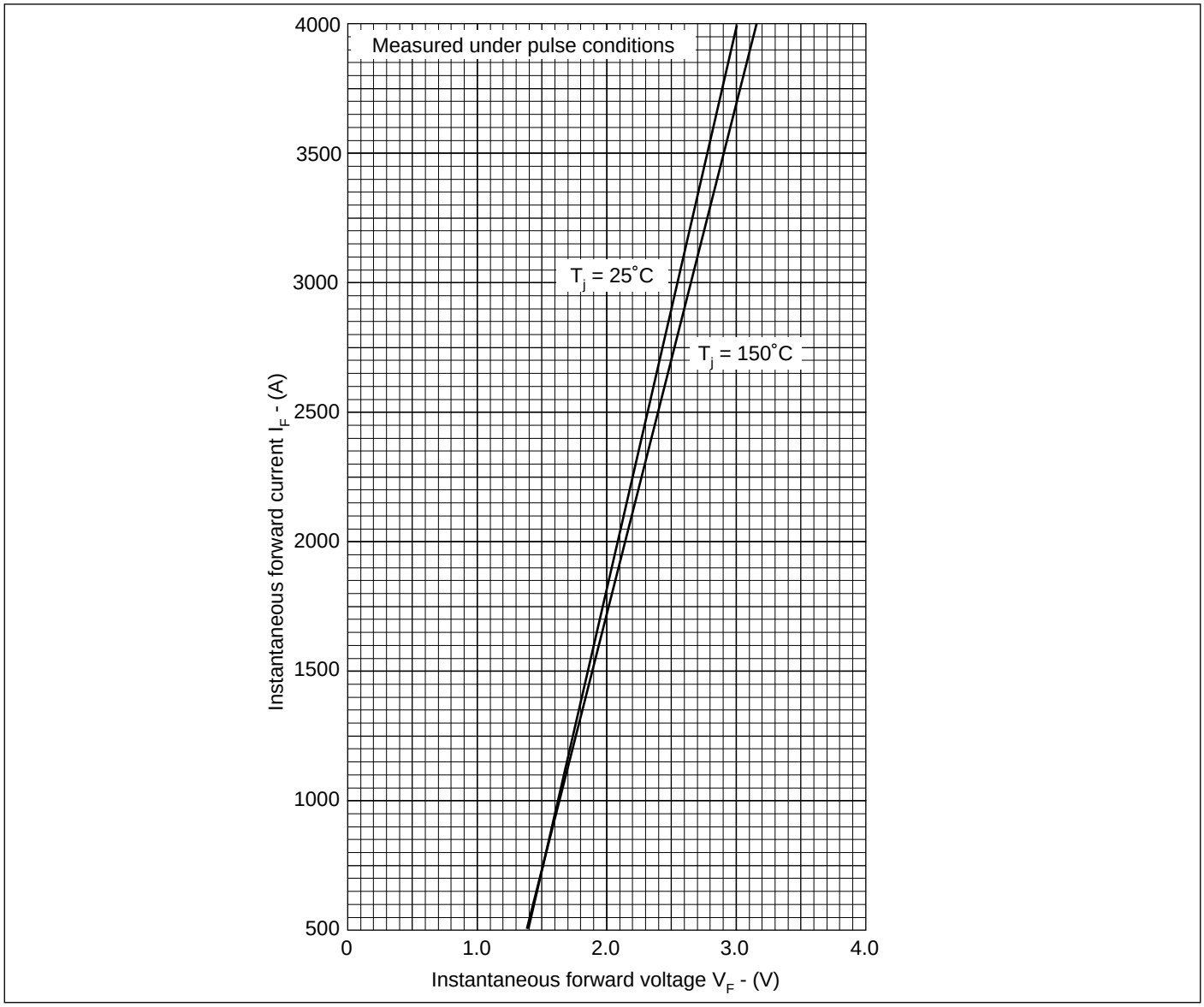


Fig.1 Maximum (limit) forward characteristics

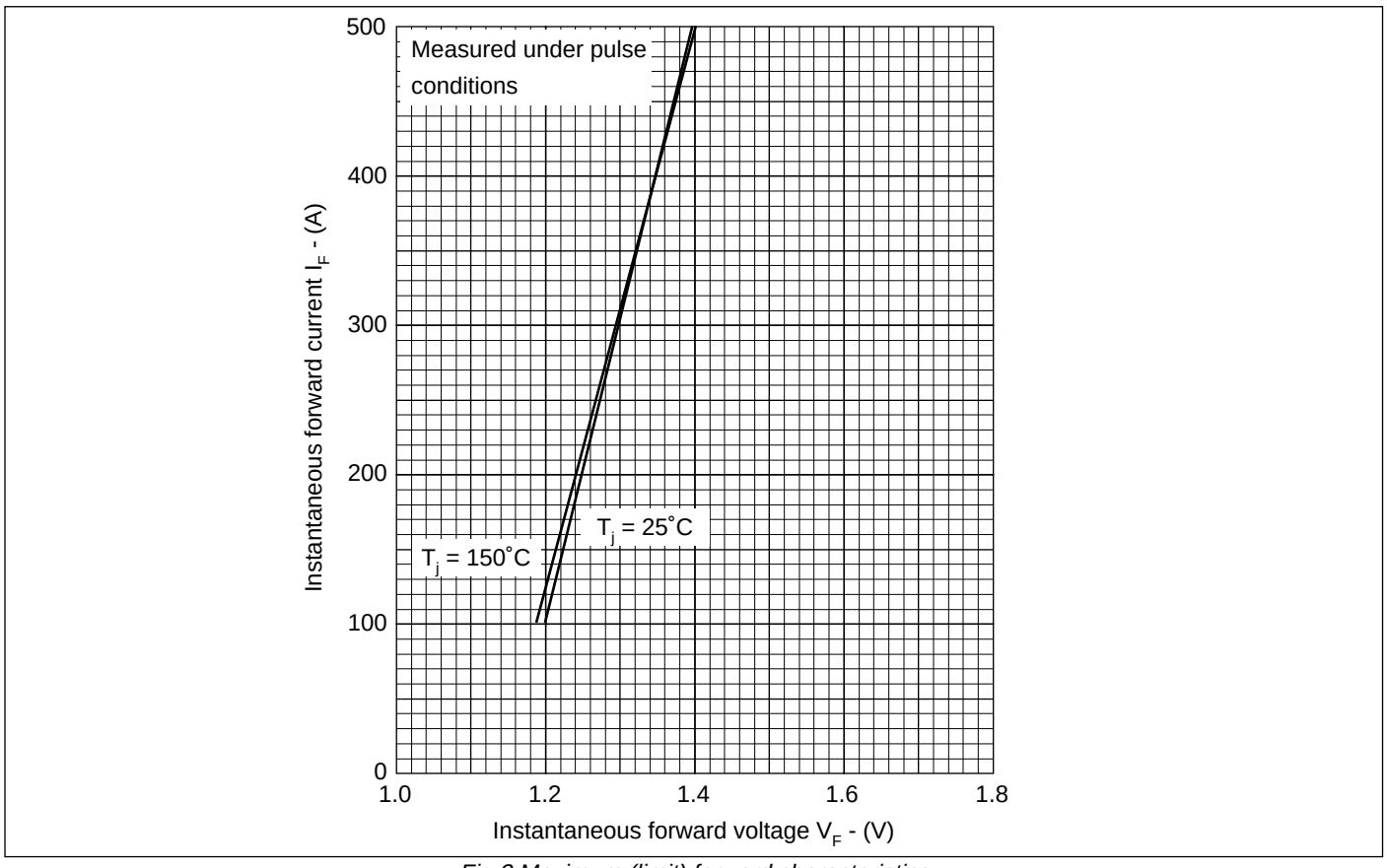


Fig.2 Maximum (limit) forward characteristics

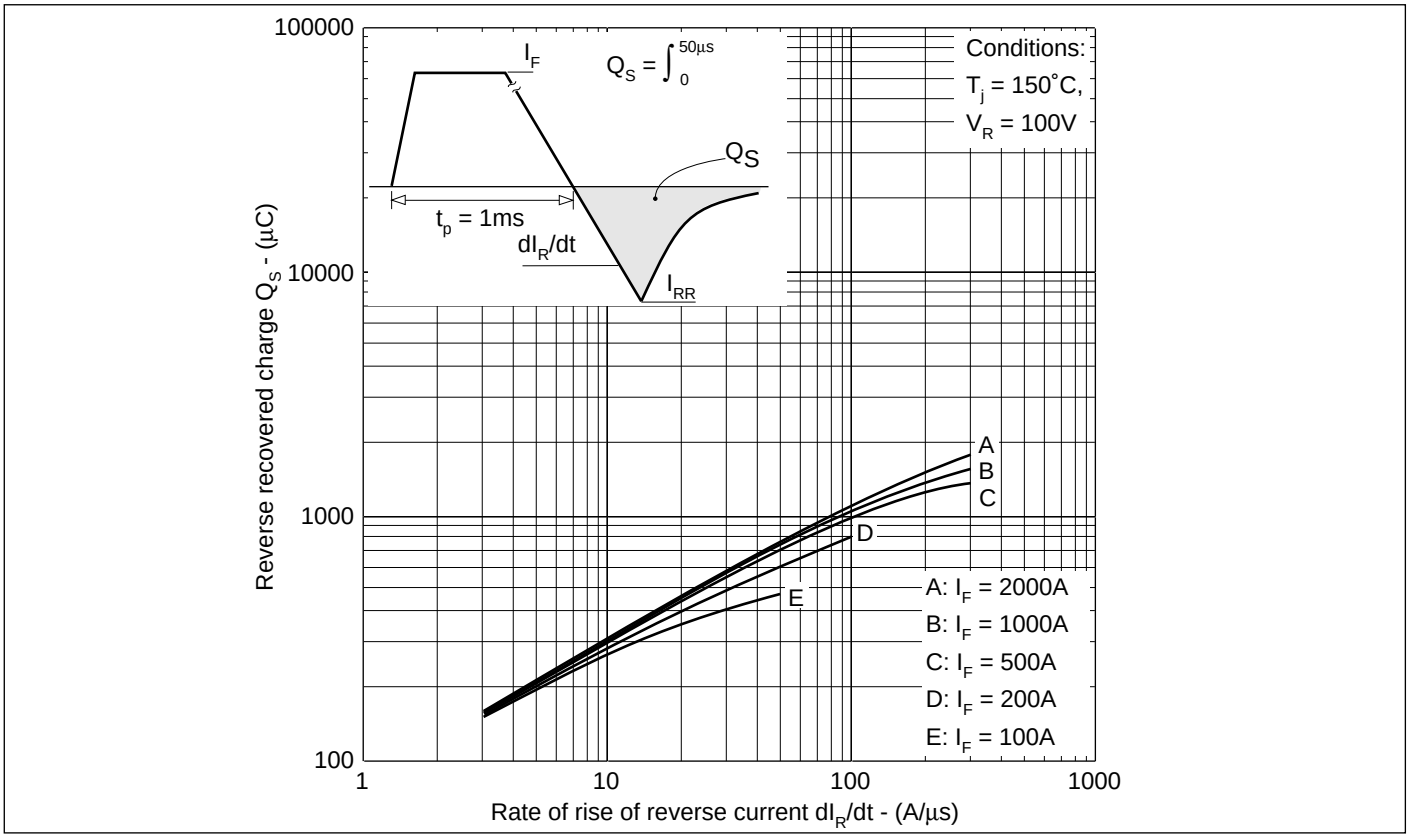


Fig.3 Recovered charge

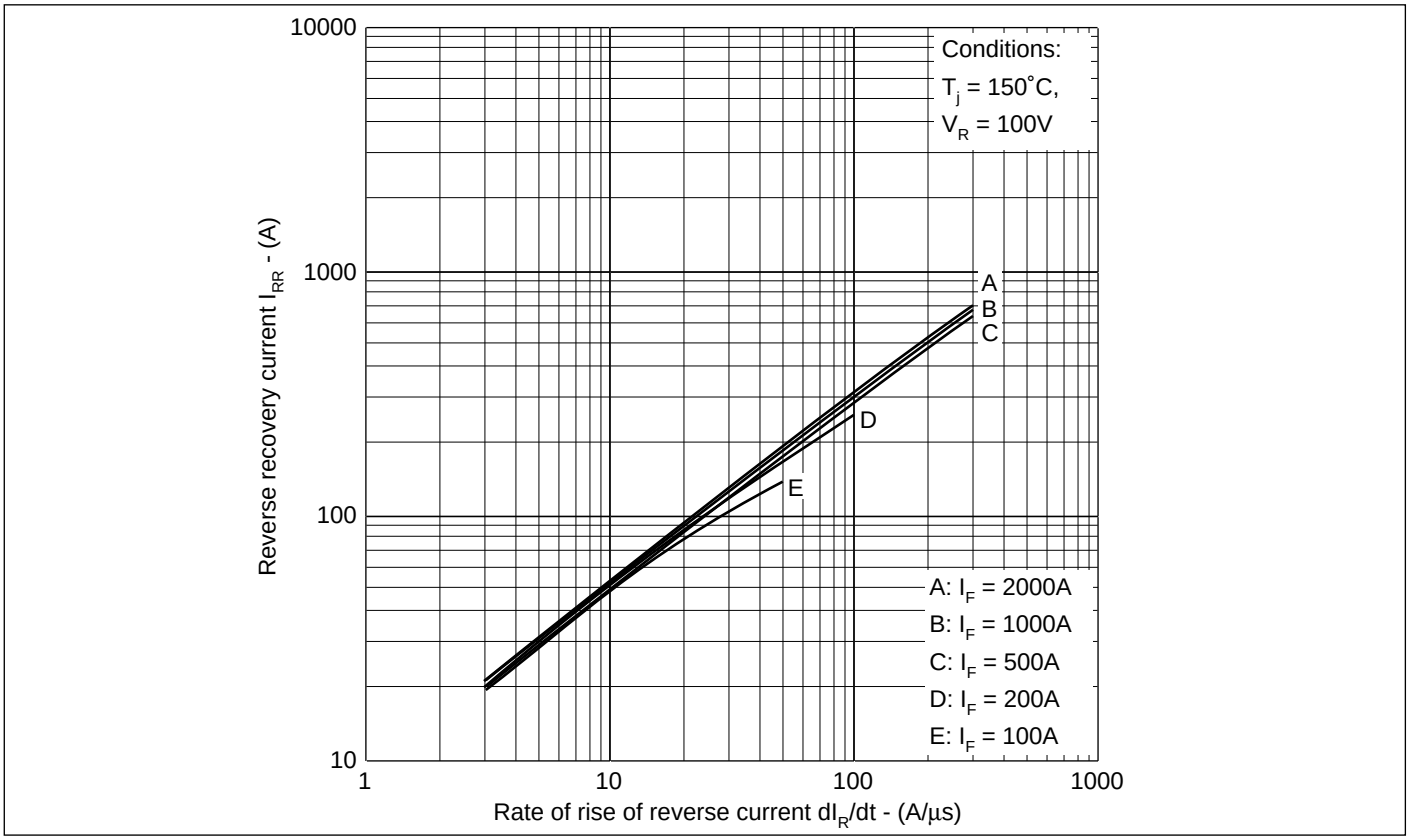


Fig.4 Typical reverse recovery current vs rate of rise of reverse current

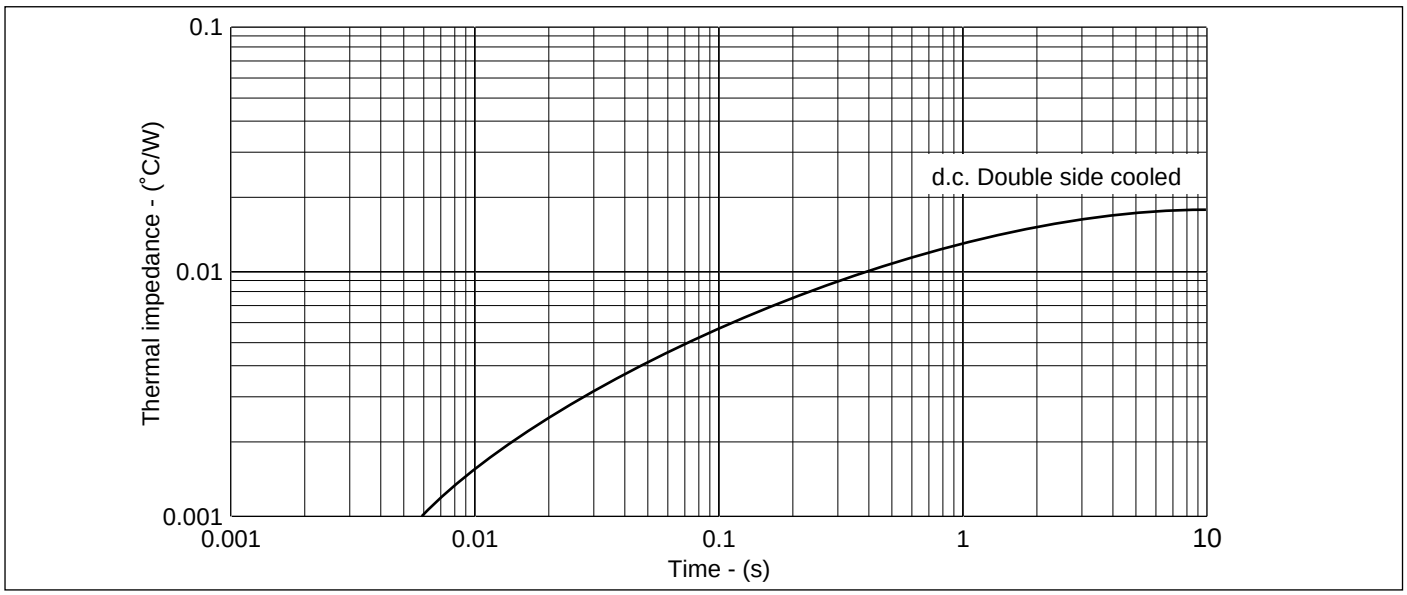
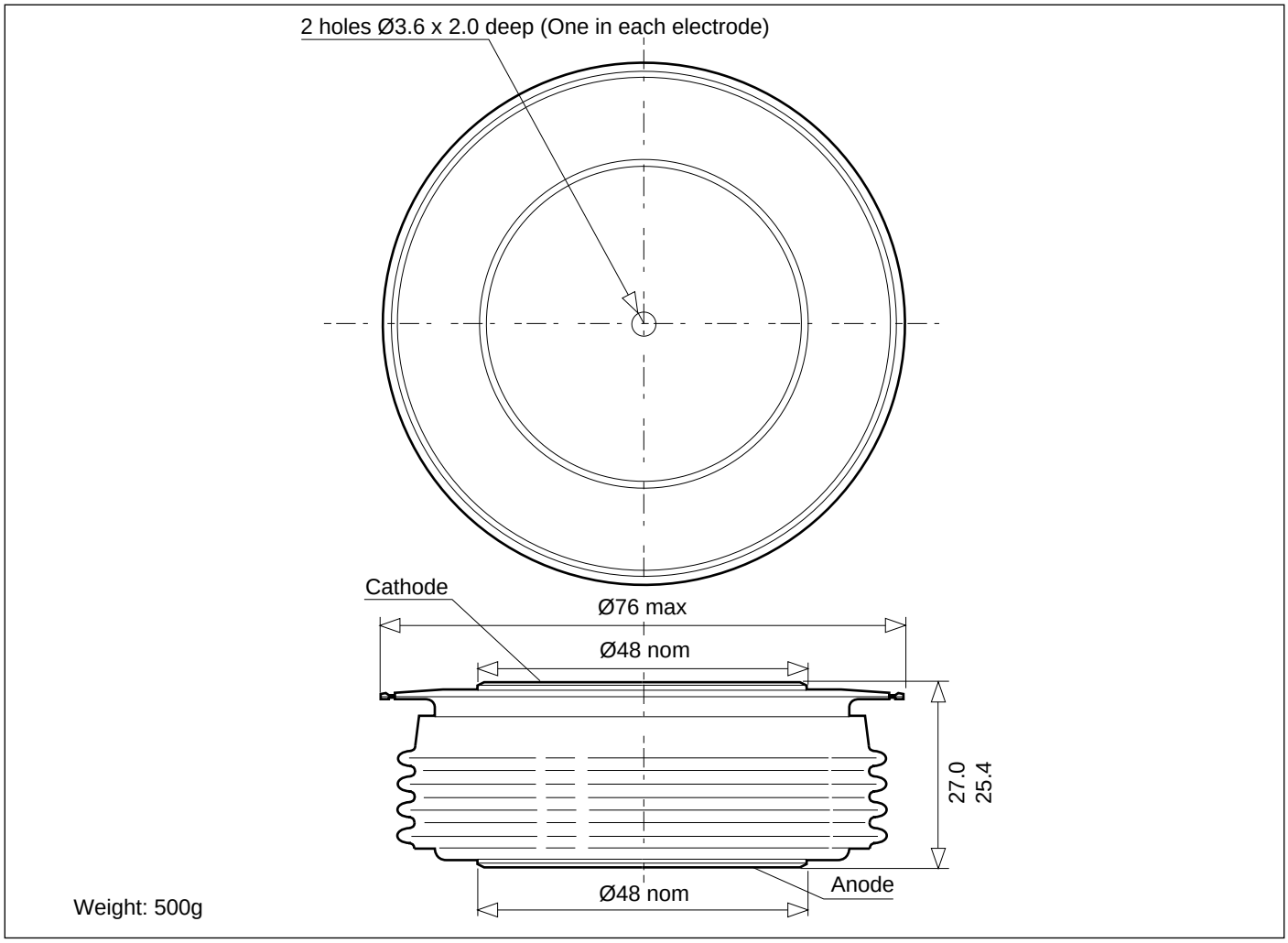


Fig.5 Maximum (limit) transient thermal impedance - junction to case - (˚C/W)

PACKAGE DETAILS - CB450

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



GEC PLESSEY SEMICONDUCTORS

HEADQUARTERS OPERATIONS

GEC PLESSEY SEMICONDUCTORS
Cheney Manor, Swindon,
Wiltshire, SN2 2QW, United Kingdom.
Tel: + 44 (0)1793 518000
Fax: + 44 (0)1793 518411

GEC PLESSEY SEMICONDUCTORS
P.O. Box 660017
1500 Green Hills Road,
Scotts Valley, California 95067-0017,
United States of America.
Tel: + 1 (408) 438 2900
Fax: + 1 (408) 438 5576

POWER PRODUCT CUSTOMER SERVICE CENTRES

- **FRANCE.** 2 rue Henri-Bergson, 92665 Asnieres Cedex.
  Tel: + 33 1 40 80 54 00. Fax: + 33 1 40 80 55 87.
- **GERMANY**. Ungererstrasse 129, 80505 München.
  Tel: + 49 (0)89 36 09 060. Fax: + 49 (0)89 36 09 06 55.
- **NORTH AMERICA.** At Dedham Place, Suite 125, 3 Allied Drive, Dedham. MA 02026.
  Tel: + 1 617 251 0126. Fax: + 1 617 251 0106.
- **UNITED KINGDOM.** Doddington Road, Lincoln. LN6 3LF.
  Tel: + 44 (0)1522 500500. Fax: + 44 (0)1522 500550.

These are supported by Agents and Distributors in major countries world-wide.

 Publication No. DS4147-4 Issue 4.2 January 1996